

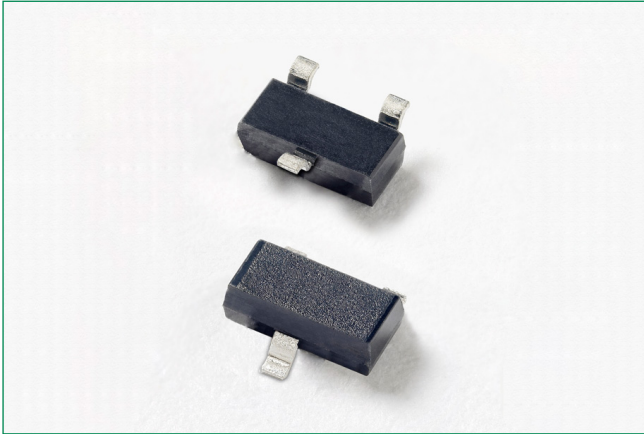


**THE DATASHEET OF  
S6X8BBSRP**



# SxX8BBS Series

## EV Series 0.8 Amp Sensitive SCRs

**HF** **RoHS****Main Features**

Symbol	Value	Unit
$I_{T(RMS)}$	0.8	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT}$	200	$\mu$ A

**Description**

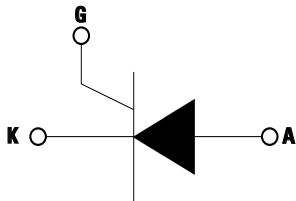
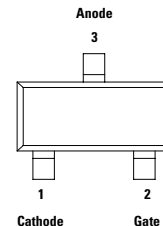
This new sensitive SCR component series offers 600V  $V_{DRM}$  and 0.8A  $I_{T(RMS)}$  capability in the smallest package size in the industry, SOT23. It is specifically designed for GFCI (Ground Fault Circuit Interrupter) applications. All SCRs junctions are glass-passivated to ensure long term reliability and parametric stability.

**Features**

- Very compact SOT23 SMT package
- Surge current capability up to 12A @ 60Hz
- Blocking voltage ( $V_{DRM}/V_{RRM}$ ) capability - up to 600V
- High dv/dt noise immunity
- Improved turn-off time ( $t_q$ ) < 25  $\mu$ sec
- Sensitive gate for direct microprocessor interface
- RoHS compliant and Halogen-Free

**Applications**

The SxX8BBS series is specifically designed for GFCI (Ground Fault Circuit Interrupter) and applications.

**Schematic Symbol****Pin out****Absolute Maximum Ratings**

Symbol	Parameter	Value	Unit	
$V_{DSM}/V_{RSM}$	Peak non-repetitive blocking voltage	Pw=100 $\mu$ s	700 V	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	$T_c = 80^\circ\text{C}$	0.8 A	
$I_{T(AV)}$	Average on-state current	$T_c = 80^\circ\text{C}$	0.51 A	
$I_{TSM}$	Non repetitive surge peak on-state current (Single cycle, $T_j$ initial = 25 $^\circ\text{C}$ )	f= 50Hz	10 A	
		f= 60Hz	12 A	
$I^2t$	$I^2t$ Value for fusing	$t_p = 10$ ms	f= 50 Hz	0.5 A <sup>2</sup> s
		$t_p = 8.3$ ms	f= 60 Hz	0.6 A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current $I_G = 10$ mA	60 Hz	$T_j = 125^\circ\text{C}$	80 A/ $\mu$ s
$I_{GM}$	Peak Gate Current	$t_p = 20$ $\mu$ s	$T_j = 125^\circ\text{C}$	1.0 A
$P_{G(AV)}$	Average gate power dissipation	—	$T_j = 125^\circ\text{C}$	0.1 W
$T_{stg}$	Storage junction temperature range	—	—	-40 to 150 $^\circ\text{C}$
$T_j$	Operating junction temperature range	—	—	-40 to 125 $^\circ\text{C}$

# SxX8BBS Series

## EV Series 0.8 Amp Sensitive SCRs

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value	Unit
$I_{GT}$	DC Gate Trigger Current	$V_D = 6\text{V}, R_L = 100\ \Omega$	MIN.	50	$\mu\text{A}$
			MAX.	200	$\mu\text{A}$
$V_{GT}$	DC Gate Trigger Voltage	$V_D = 6\text{V}, R_L = 100\ \Omega$	MAX.	0.8	V
$V_{GRM}$	Peak Reverse Gate Voltage	$I_{RG} = 10\ \mu\text{A}$	MIN.	8	V
$I_H$	Holding Current	Initial Current = 20mA	MAX.	10	mA
(dv/dt)s	Critical Rate-of-Rise of Off-State Voltage	$T_J = 125^\circ\text{C}$ $V_D = 67\%V_{DRM}/V_{RRM}$ Exp. Waveform, $R_{GK} = 1\ \text{k}\Omega$	MIN.	50	V/ $\mu\text{s}$
$V_{GD}$	Gate Non-Trigger Voltage	$V_D = V_{DRM}, R_{GK} = 1\ \text{k}\Omega$ $T_J = 125^\circ\text{C}$	MIN.	0.2	V
$t_q$	Turn-Off Time	$I_T = 0.5\text{A}$	MAX.	25	$\mu\text{s}$
$t_{gt}$	Turn-On Time	$I_G = 10\text{mA}, P_w = 15\ \mu\text{sec},$ $I_T = 1.6\text{A(pk)}$	TYP.	2.0	$\mu\text{s}$

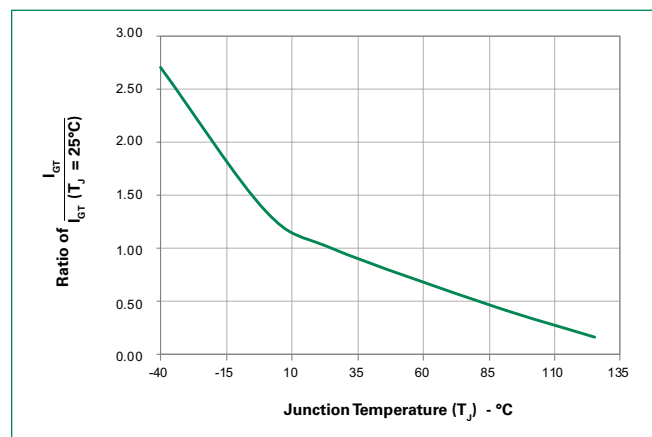
### Static Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value	Unit
$V_{TM}$	Peak On-State Voltage	$I_{TM} = 1.6\text{A (pk)}$	MAX.	1.70	V
$I_{DRM}/I_{RRM}$	$V_{DRM}/V_{RRM}$	$T_J = 25^\circ\text{C}$	MAX.	5	$\mu\text{A}$
		$T_J = 125^\circ\text{C}$	MAX.	100	$\mu\text{A}$

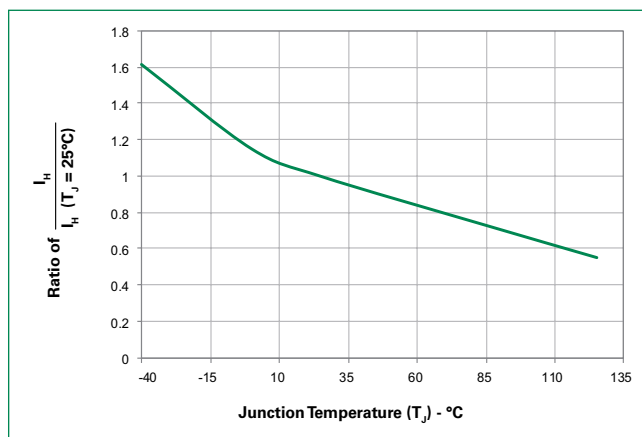
### Thermal Resistances

Symbol	Description	Value	Unit
$R_{\Theta(JC)}$	Junction to case (AC)	45	$^\circ\text{C/W}$
$R_{\Theta(JA)}$	Junction to ambient	220	$^\circ\text{C/W}$

**Figure 1:**  
Normalized DC Gate Trigger Current vs.  
Junction Temperature



**Figure 2:**  
Normalized DC Holding Current vs.  
Junction Temperature

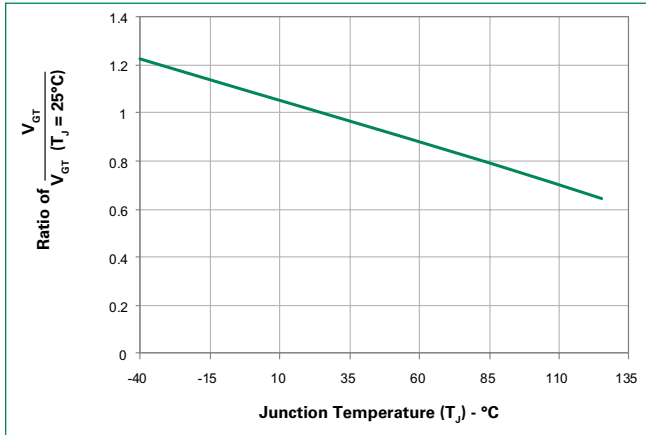


# SxX8BBS Series

## EV Series 0.8 Amp Sensitive SCRs

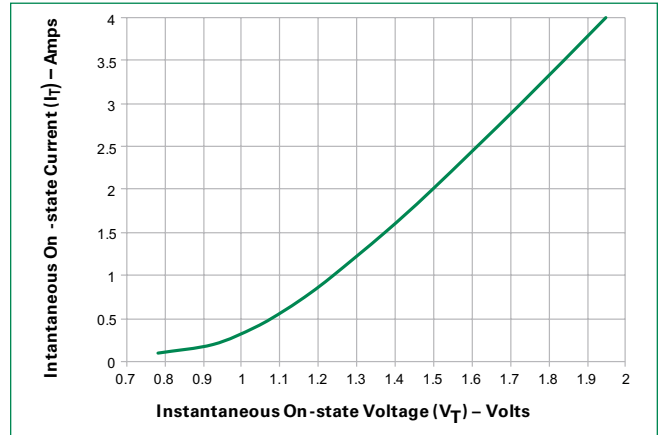
**Figure 3:**

Normalized DC Gate Trigger Voltage vs. Junction Temperature



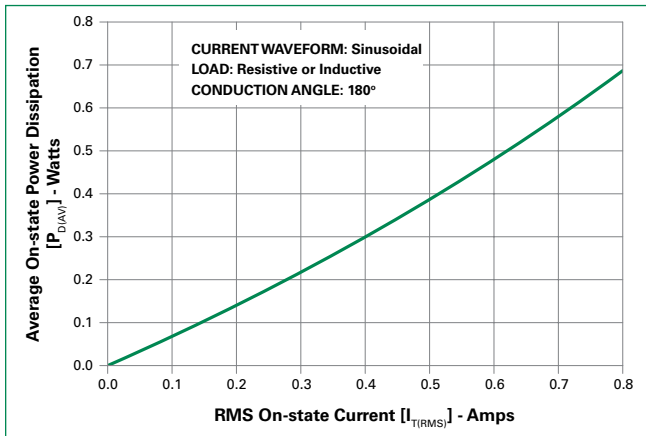
**Figure 4:**

On-State Current vs. On-State Voltage (Typical)



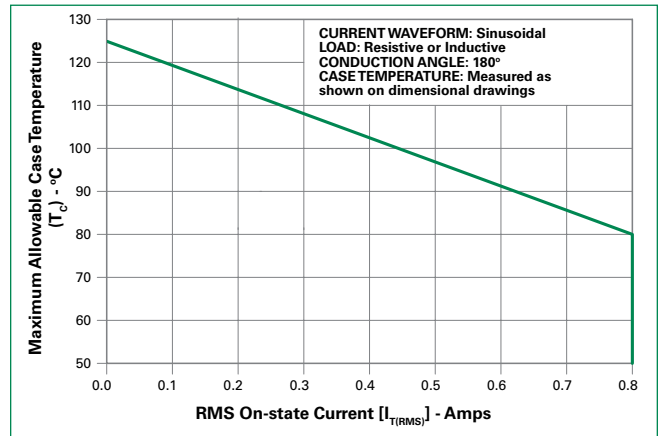
**Figure 5:**

Power Dissipation (Typical) vs. RMS On-State Current

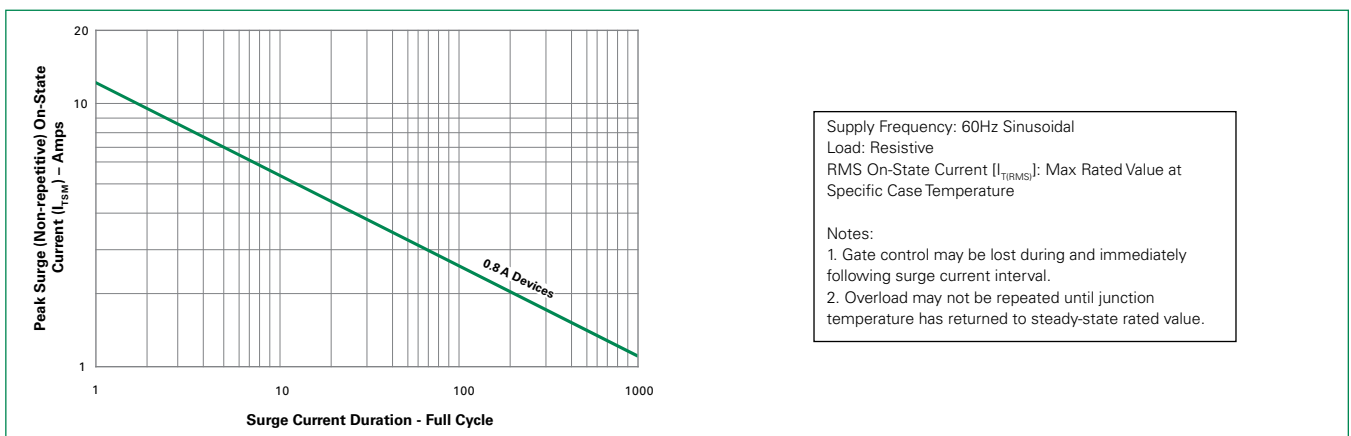


**Figure 6:**

Maximum Allowable Case Temperature vs. On-State Current



**Figure 7:** Surge Peak On-State Current vs. Number of Cycles



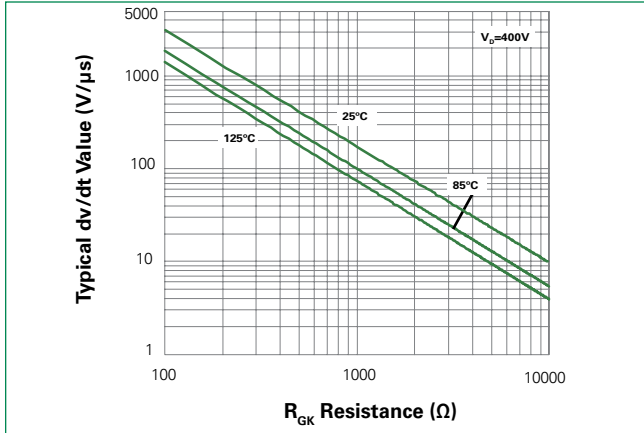
Supply Frequency: 60Hz Sinusoidal  
 Load: Resistive  
 RMS On-State Current [ $I_{T(RMS)}$ ]: Max Rated Value at Specific Case Temperature

Notes:  
 1. Gate control may be lost during and immediately following surge current interval.  
 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

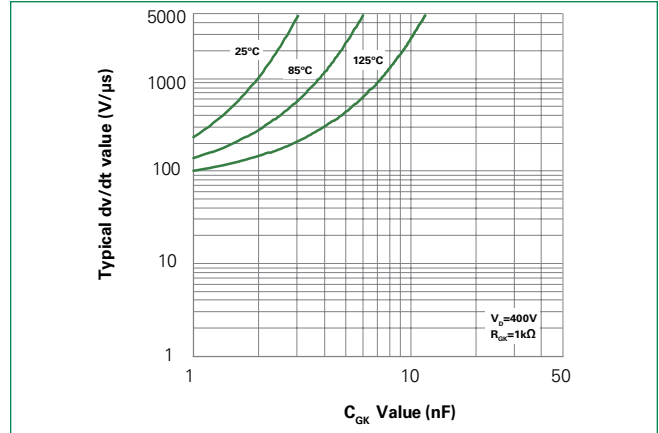
# SxX8BBS Series

## EV Series 0.8 Amp Sensitive SCRs

**Figure 8:**  
Static dv/dt vs. RGK vs. Junction Temperature

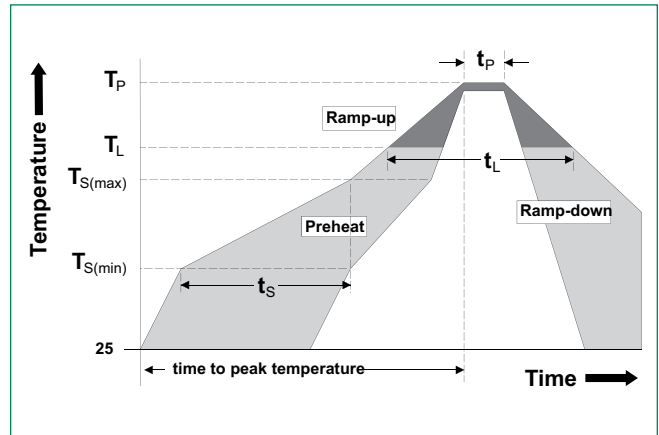


**Figure 9:**  
Static dv/dt vs. CGK vs. Junction Temperature



### Soldering Parameters

<b>Reflow Condition</b>		Pb – Free assembly
<b>Pre Heat</b>	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 120 secs
<b>Average ramp up rate (Liquidus Temp) (<math>T_L</math>) to peak</b>		3°C/second max
<b><math>T_{s(max)}</math> to <math>T_L</math> - Ramp-up Rate</b>		5°C/second max
<b>Reflow</b>	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Time (min to max) ( $t_s$ )	60 – 150 seconds
<b>Peak Temperature (<math>T_p</math>)</b>		260 <sup>+0/-5</sup> °C
<b>Time within 5°C of actual peak Temperature (<math>t_p</math>)</b>		30 seconds
<b>Ramp-down Rate</b>		6°C/second max
<b>Time 25°C to peak Temperature (<math>T_p</math>)</b>		8 minutes Max.
<b>Do not exceed</b>		260°C



# SxX8BBS Series

## EV Series 0.8 Amp Sensitive SCRs

### Physical Specifications

<b>Terminal Finish</b>	100% Matte Tin-plated.
<b>Body Material</b>	UL Recognized compound meeting flammability rating V-0.
<b>Lead Material</b>	Copper Alloy

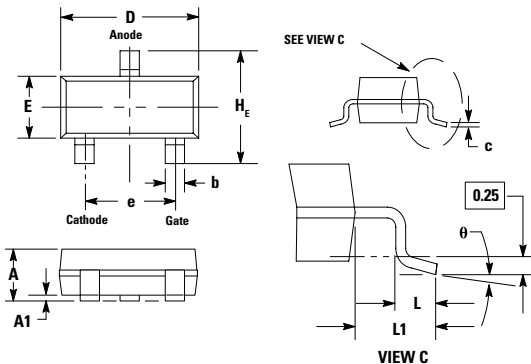
### Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including  $dv/dt$ ), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

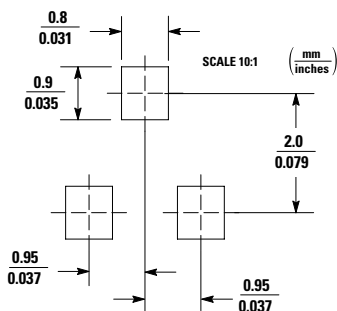
### Reliability/Environmental Tests

Test	Specifications and Conditions
<b>HTRB (AC Blocking)</b>	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ $V_{DRM}$ @ 125°C for 1008 hours
<b>Temperature Cycling</b>	MIL-STD-750, M-1051, 100 cycles; -55°C to +150°C; 15-min dwell-time
<b>H3TRB</b>	EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC; 85°C; 85% rel humidity
<b>UHASt</b>	ESD22-A118, 96hours, 130°C, 85%RH
<b>Resistance to Solder Heat</b>	MIL-STD-750 Method 2031, 260°C, 10s
<b>Solderability</b>	ANSI/J-STD-002, category 3, Test A
<b>Moisture Sensitivity Level</b>	Level 1, JEDEC-J-STD-020D

### Dimensions – SOT-23



#### SOLDERING FOOTPRINT



Dimensions	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
<b>A</b>	0.04	0.04	0.04	0.89	1.02	1.12
<b>A1</b>	0.00	0.00	0.01	0.01	0.10	0.15
<b>b</b>	0.02	0.02	0.02	0.38	0.46	0.51
<b>c</b>	0.00	0.01	0.01	0.08	0.13	0.18
<b>D</b>	0.11	0.11	0.12	2.80	2.90	3.04
<b>E</b>	0.05	0.05	0.06	1.19	1.30	1.40
<b>e</b>	0.07	0.08	0.08	1.78	1.91	2.06
<b>L</b>	0.02	0.02	0.02	0.40	0.49	0.60
<b>L1</b>	0.01	0.02	0.03	0.36	0.53	0.74
<b>H</b>	0.08	0.09	0.10	2.10	2.30	2.64
<b>θ</b>	0°	-	10°	0°	-	10°

### Product Selector

Part Number	Voltage 600V	Gate Sensitivity	Package
S6X8BBS	X	200 $\mu$ A	SOT-23

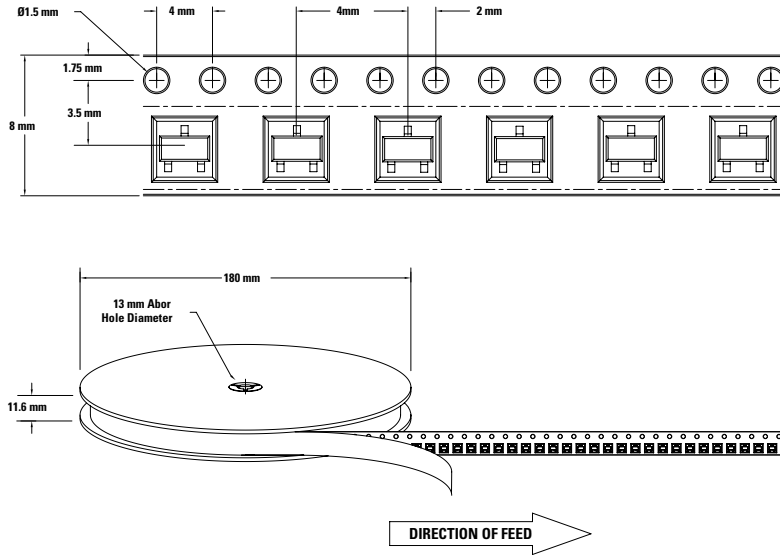
### Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
S6X8BBSRP	6X8	0.01g	Tape & Reel	3000

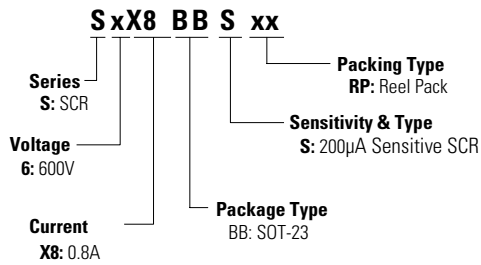
# SxX8BBS Series

## EV Series 0.8 Amp Sensitive SCRs

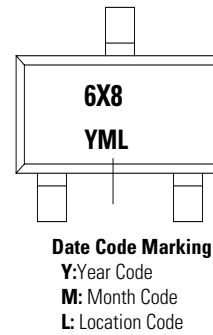
### SOT-23 Reel Pack (RP) Specifications



### Part Numbering System



### Part Marking System



**Disclaimer Notice** - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <http://www.littelfuse.com/disclaimer-electronics>.

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View S6X8BBSRP on WIN SOURCE](#)

 [Littelfuse Inc. Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management